

PRODUCT / PROCESS CHANGE NOTIFICATION

1. PCN basic data

1.1 Company	 STMicroelectronics International N.V
1.2 PCN No.	POWER AND DISCRETES/25/15483
1.3 Title of PCN	Front-End manufacturing Transfer for 8 inches Wafer Diameter Conversion for 650V G serie SiC Diodes from ST Catania (Italy) to SSTF-Sanan (China) and EWS Transfer from ST Catania (Italy) to ST Shenzhen (China)
1.4 Product Category	SiC Diodes
1.5 Issue date	2025-07-24

2. PCN Team

2.1 Contact supplier	
2.1.1 Name	ROBERTSON HEATHER
2.1.2 Phone	+1 8475853058
2.1.3 Email	heather.robertson@st.com
2.2 Change responsibility	
2.2.1 Product Manager	Stephane CHAMARD
2.1.2 Marketing Manager	Philippe LEGER
2.1.3 Quality Manager	Jean-Paul REBRASSE

3. Change

3.1 Category	3.2 Type of change	3.3 Manufacturing Location
Manufacturing reshaping program	Manufacturing reshaping program	6" ST Catania (Italy) with EWS in ST Catania (Italy) 8" SSTF-Sanan (China) with EWS in ST Shenzhen (China)

4. Description of change

	Old	New
4.1 Description	6" ST Catania (Italy) with EWS in ST Catania (Italy)	8" SSTF-Sanan (China) with EWS in ST Shenzhen (China)
4.2 Anticipated Impact on form,fit, function, quality, reliability or processability?	No impact	

5. Reason / motivation for change

5.1 Motivation	Following Corporate PCI 15383 (Early Notification), about Company reshaping program, please be informed that Die manufacturing line in 6 inches at ST Catania (Italy) for SiC Diodes products listed here below will be transferred to 8 inches wafer diameter in SSTF-Sanan (China) and EWS Transfer from ST Catania (Italy) to ST Shenzhen (China).
5.2 Customer Benefit	SERVICE CONTINUITY

6. Marking of parts / traceability of change

6.1 Description	Traceability of the change will be ensured by Finished Good/Type (Beginning with O letter) printed on carton labels.
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7. Timing / schedule

7.1 Date of qualification results	2026-07-31
7.2 Intended start of delivery	2026-12-31
7.3 Qualification sample available?	Upon Request

8. Qualification / Validation

8.1 Description			
8.2 Qualification report and qualification results	In progress	Issue Date	

9. Attachments (additional documentations)		
15483 Public product.pdf 15483 SiC Diodes 650 G Sanan.pdf		

10. Affected parts		
10. 1 Current		10.2 New (if applicable)
10.1.1 Customer Part No	10.1.2 Supplier Part No	10.1.2 Supplier Part No
	STPSC20G065WL	
	STPSC20G065WLY	
	STPSC30G065WL	
	STPSC30G065WLY	
	STPSC4G065UF	
	STPSC4G065UFY	

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